

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Super Trench
- ☒ T_J max 175°C
- ☒ Advanced trench cell design
- ☒ MSL1

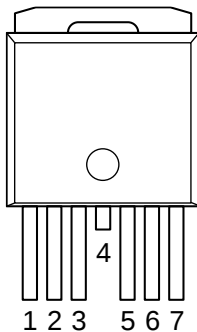
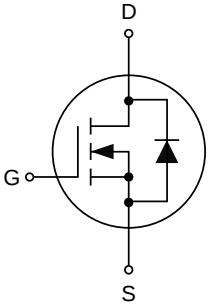
1.2 Applications

- ☒ Power Tool appliances
- ☒ BMS appliances
- ☒ High power inverter system

1.3 Quick reference

- ☒ $BV \geq 150\text{ V}$
- ☒ $P_D \leq 300\text{ W}$
- ☒ $I_D \leq 220\text{ A}$
- ☒ $R_{DS(ON)} \leq 5.0\text{ m}\Omega @V_{GS} = 10\text{ V}$
- ☒ $R_{DS(ON)} \leq 6.0\text{ m}\Omega @V_{GS} = 6\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO263-7L	
2, 3	Source(S)		
4	Drain(D)		
5, 6, 7	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C=25^{\circ}\text{C}$	-	150	V
V_{GS}	Gate-Source Voltage	$T_C=25^{\circ}\text{C}$	-	± 20	V
I_D^*	Drain Current (DC)	$T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	220	A
		$T_C=100^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	120	A
I_{DM}^*	Drain Current (Pulsed)	$T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	600	A
P_{tot}	Drain Power Dissipation	$T_C=25^{\circ}\text{C}$	-	300	W
I_S	Continuous-Source Current	$T_C=25^{\circ}\text{C}$	-	220	A
E_{AS}^*	Single Pulsed Avalanche Energy	$V_{DD}=50\text{ V}, L=1.0\text{ mH}$	-	1300	mJ
T_J, T_{stg}	Operating Junction and Storage Temperature		-55	175	$^{\circ}\text{C}$
$R_{\theta JA}^{**}$	Thermal Resistance-Junction to Ambient		-	40	$^{\circ}\text{C/W}$
$R_{\theta JC}$	Thermal Resistance-Junction to Case		-	0.5	$^{\circ}\text{C/W}$

Notes:

- * Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- ** Surface mounted on 1 in^2 pad area, $t \leq 10\text{ sec}$.
- *** Limited by bonding wire.

4. Marking Information

Product Name	Marking
KJ0515D7	KJ0515D7 AYWWXX XXXXXX

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity
KJ0515D7	TO263-7L	13"	24 mm	800

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

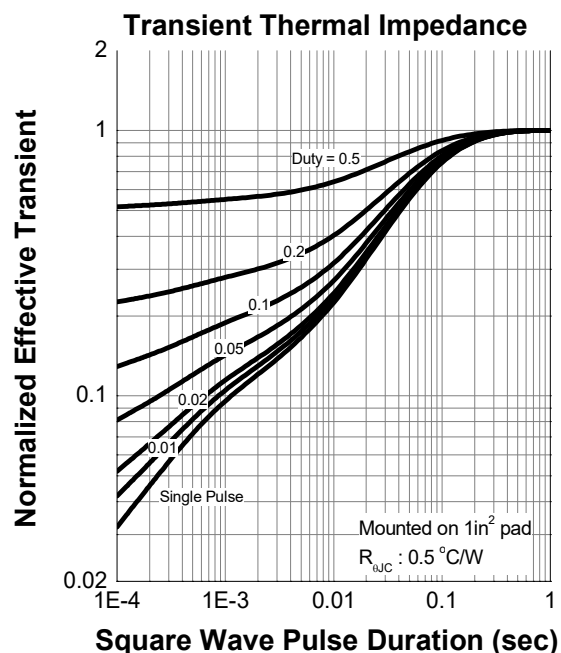
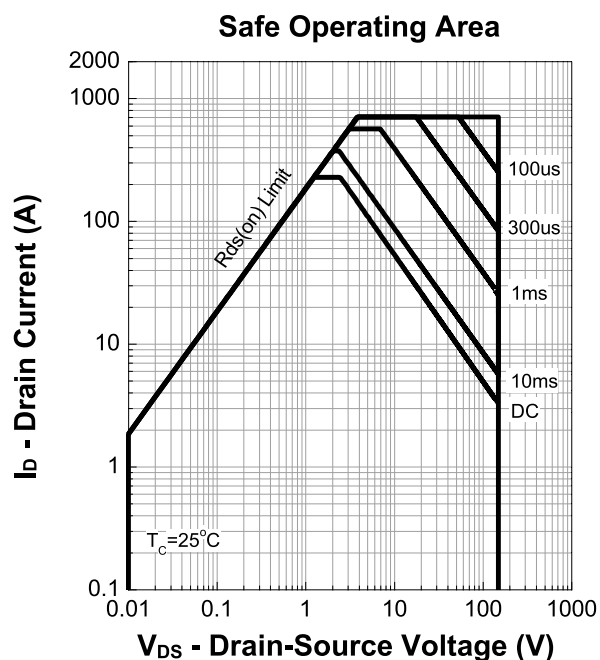
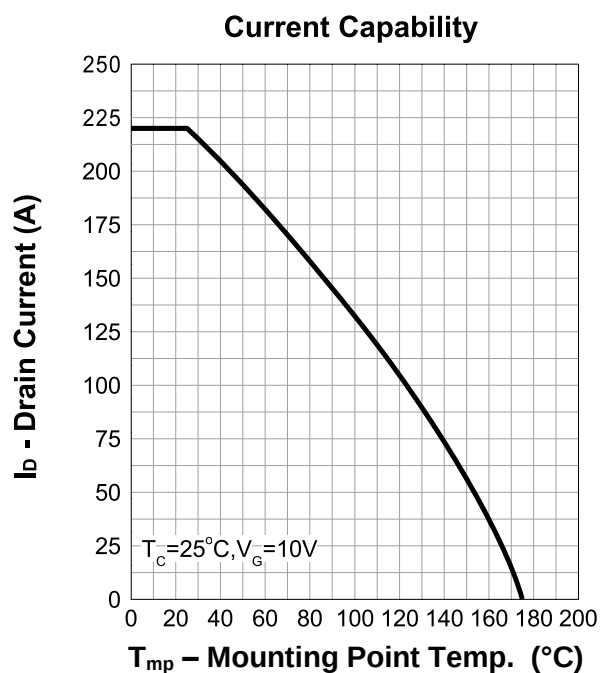
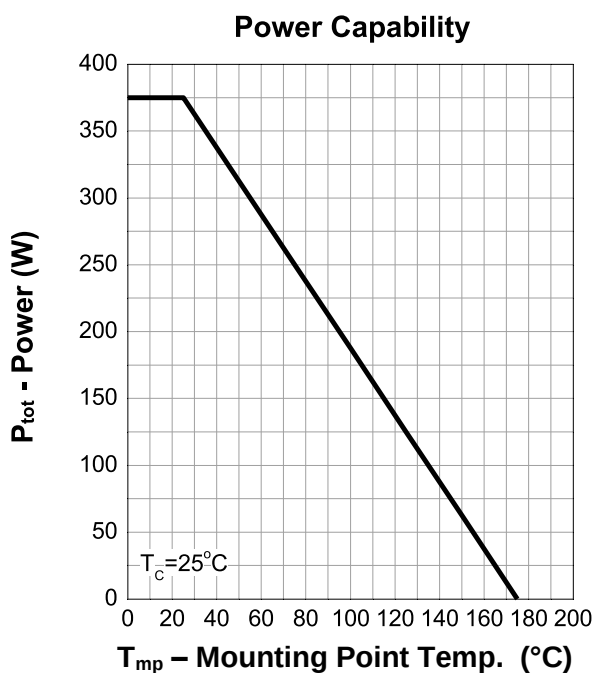
6. Electrical Characteristics (T_A=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _{DS} =250 μA	150	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	2	-	4	V
I _{DSS}	Drain Leakage Current	V _{DS} =120 V, V _{GS} =0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} =0 V, V _{GS} =±20 V	-	-	±100	nA
R _{DS(ON)} ^a	On-State Resistance	V _{GS} =10 V, I _{DS} =50 A	-	4.6	5.1	mΩ
		V _{GS} =6 V, I _{DS} =30 A	-	5.3	6.2	mΩ
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	I _{SD} =50 A, V _{GS} =0 V	-	-	1.3	V
t _{rr}	Reverse Recovery Time	I _{SD} =50 A, V _{GS} =0 V, dI _{SD} /dt=100 A/μs	-	114	-	ns
Q _{rr}	Reverse Recovery Charge		-	355	-	nC
Dynamic Characteristics ^b						
C _{iss}	Input Capacitance	V _{GS} =0 V, V _{DS} =75 V, Frequency=1 MHz	-	8562	-	pF
C _{oss}	Output Capacitance		-	562	-	
C _{rss}	Reverse Transfer Capacitance		-	63	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =75 V, V _{GEN} =10 V, R _G =3.9 Ω, R _L =1.5 Ω, I _{DS} =50 A	-	23	-	ns
t _r	Turn-on Rise Time		-	79	-	
t _{d(off)}	Turn-off Delay Time		-	77	-	
t _f	Turn-off Fall Time		-	85	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} =75 V, V _{GS} =10 V, I _{DS} =50 A	-	124	-	nC
Q _{gs}	Gate-Source Charge		-	47	-	
Q _{gd}	Gate-Drain Charge		-	19	-	

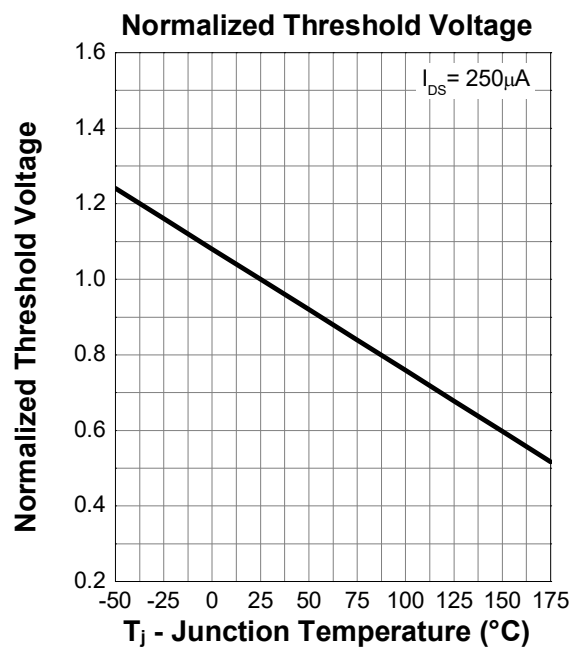
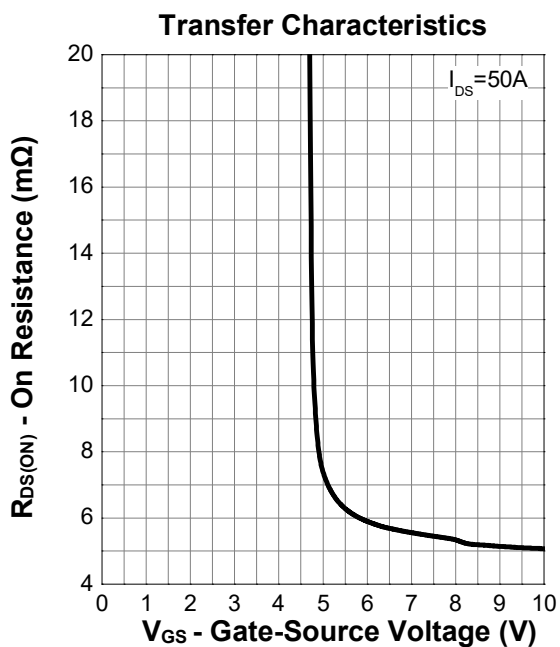
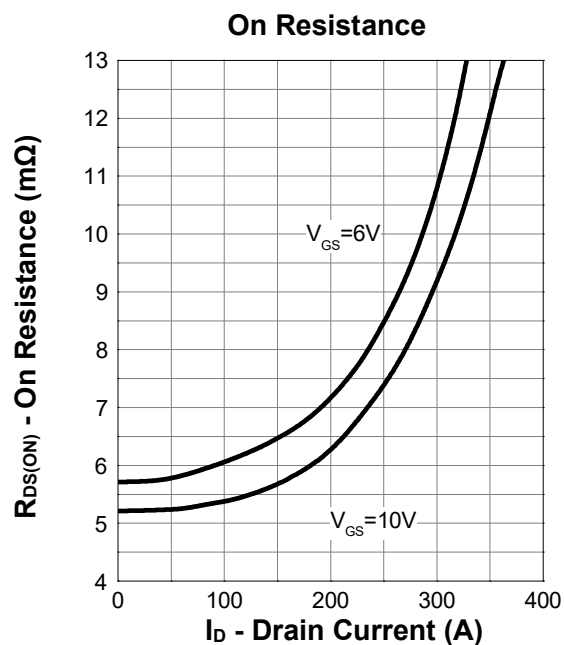
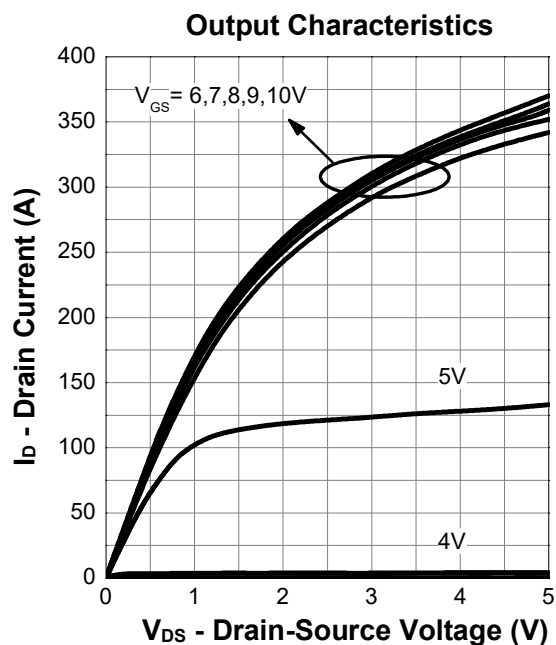
Notes:

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.

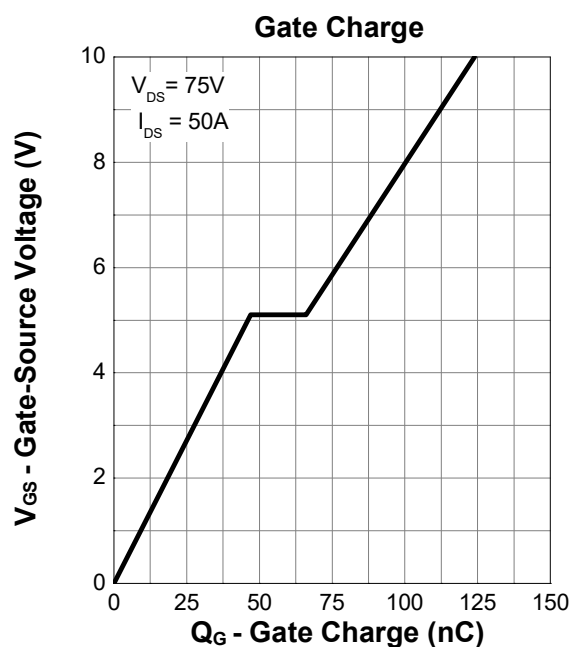
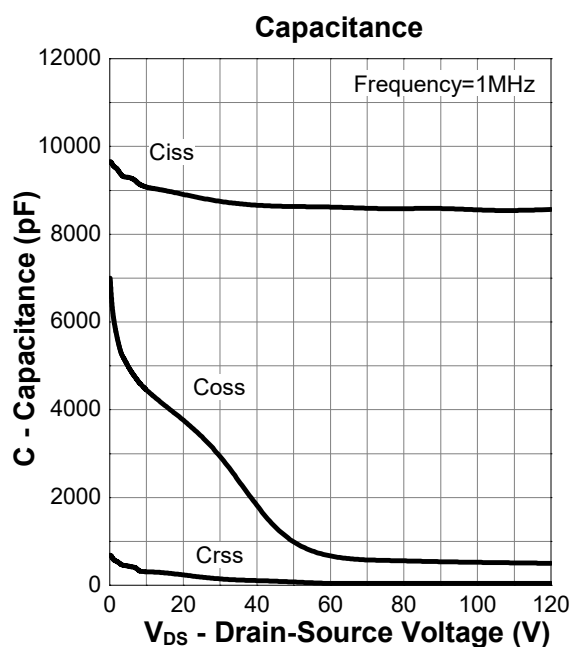
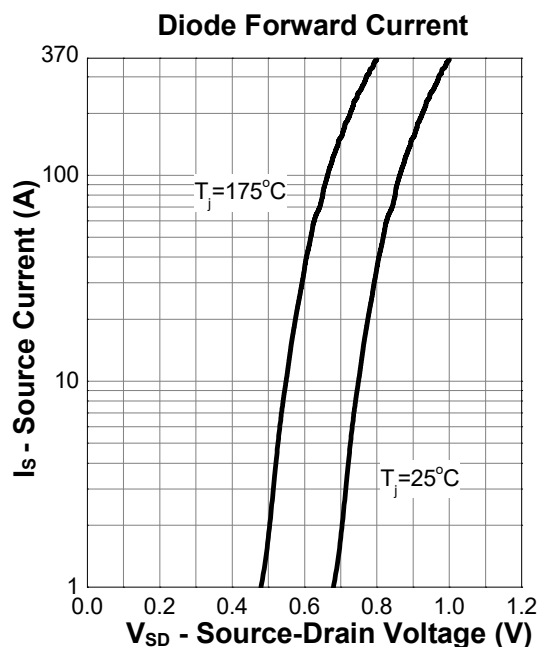
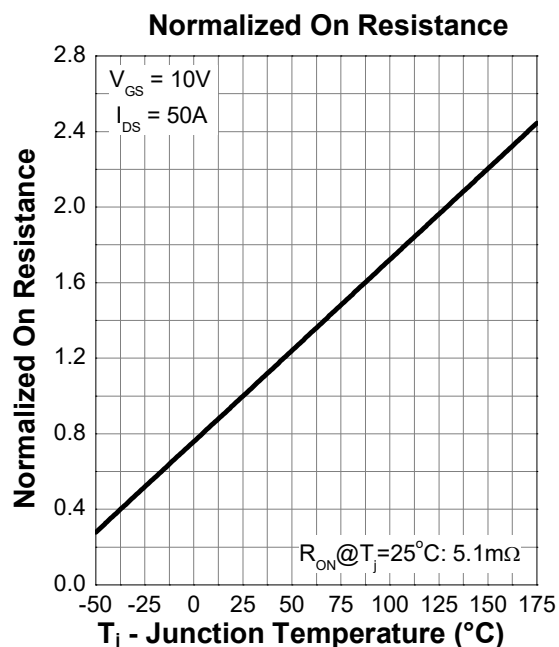
7. Typical Characteristics



7. Typical Characteristics (cont.)

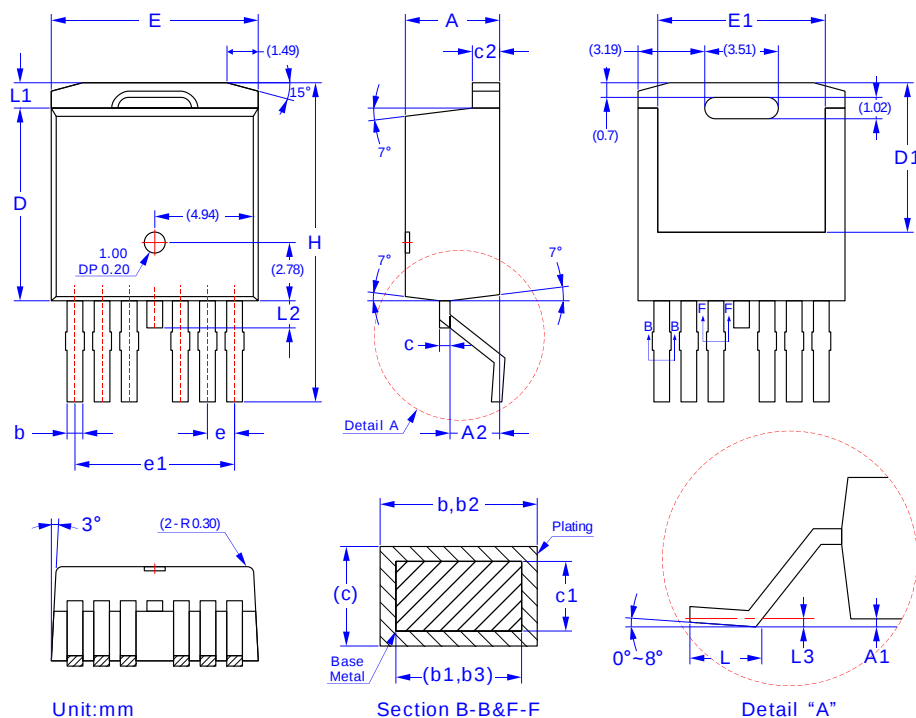


7. Typical Characteristics (cont.)



8. Package Dimensions

TO263-7L Package



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	4.30	4.70
A1	-	0.25
A2	2.20	2.60
b	0.65	0.85
b1	0.65	0.80
b2	0.80	1.00
b3	0.80	0.95
c	0.45	0.60
c1	0.45	0.55
c2	1.25	1.40
D	9.00	9.40
D1	6.86	7.42
E	9.68	10.08
E1	7.70	8.30
e	1.27 BSC	
e1	7.62 BSC	
L	1.78	2.79
L1	-	1.60
L2	-	1.78
L3	0.25 BSC	
H	14.61	15.88